

TDS:EMIC

拓 電 半 導 體

自主封測 品質把控 售後保障

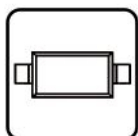
WEB | WWW.TDSEMIC.COM



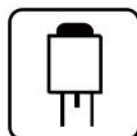
電源管理



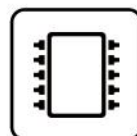
顯示驅動



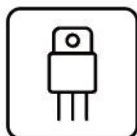
二三極管



LDO穩壓器



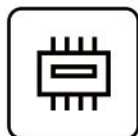
觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

SS34C-TD

產品規格說明書

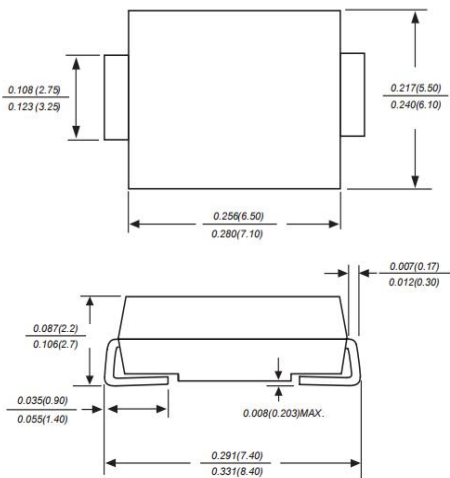
SS52 THRU SS520

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 5.0 Amperes

SMC

DO-214AB



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AB molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.008 ounce, 0.217 grams

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SS52	SS53	SS54	SS55	SS56	SS59	SS510	SS515	SS520	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	90	100	150	200	VOLTS
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	63	70	105	140	VOLTS
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	90	100	150	200	VOLTS
Maximum average forward rectified current at T _L (see fig.1)	I _(AV)	5.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150.0									Amps
Maximum instantaneous forward voltage at 5.0A	V _F	0.45	0.55		0.70		0.85				Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5					0.1				mA
		20									
Typical junction capacitance (NOTE 1)	C _J	800									pF
Typical thermal resistance (NOTE 2)	R _{qJA}	40.0									°C/W
Operating junction temperature range	T _J	-65 to +125			-65 to +150						°C
Storage temperature range	T _{STG}	-65 to +150									°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.6x0.6" (16x16mm) copper pad areas

